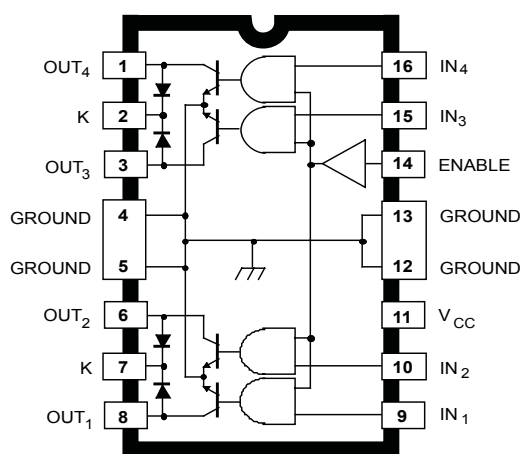


PROTECTED QUAD POWER DRIVER

UDx2559B



Dwg. PP-017-1

ABSOLUTE MAXIMUM RATINGS

at $T_A = 25^\circ\text{C}$

Output Voltage, V_{OUT}	60 V
Over-Current Protected Output Voltage, V_{OUT}	25 V
Output Current, I_{OUT}	1.0 A*
Supply Voltage, V_{CC}	7.0 V
Input Voltage, V_{IN} or V_{EN}	7.0 V
Package Power Dissipation, P_D	See Graph
Operating Temperature Range, T_A	
Prefix 'UDK'	-40°C to $+125^\circ\text{C}$
Prefix 'UDN'	-20°C to $+85^\circ\text{C}$
Prefix 'UDQ'	-40°C to $+85^\circ\text{C}$
Storage Temperature Range, T_S	-55°C to $+150^\circ\text{C}$

*Outputs are peak current limited at approximately 1.0 A per driver. See Circuit Description and Application for further information.

Providing improved output current limiting, the UDK, UDN, and UDQ2559B, EB, and LB quad power drivers combine AND logic gates and high-current bipolar outputs with complete output protection. Each of the four outputs will sink 700 mA in the on state. The outputs have a minimum breakdown voltage (load dump) of 60 V and a sustaining voltage of 40 V. The inputs are compatible with TTL and 5 V CMOS logic systems.

Over-current protection for each channel has been designed into these devices and is activated at approximately 1 A. It protects each output from short circuits with supply voltages up to 25 V. When an output current trip point is reached, that output stage is driven linearly resulting in a reduced output current level. If an over-current or short-circuit condition continues, the thermal-limiting circuits will first sense the rise in junction temperature and then the rise in chip temperature, further decreasing the output current. Under worst-case conditions, these devices will tolerate short circuits on all outputs, simultaneously.

These devices can be used to drive various loads including incandescent lamps (without warming or limiting resistors) or inductive loads such as relays, solenoids, or dc stepping motors.

The packages offer fused leads for enhanced thermal dissipation. Package B is a 16-pin power DIP with exposed tabs, EB is a 28-lead power PLCC, and LB is a 16-lead power wide-body SOIC for surface-mount applications. The lead (Pb) free versions have 100% matte tin leadframe plating.

FEATURES

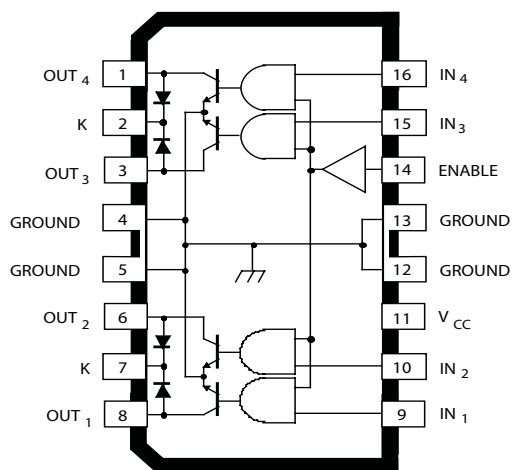
- 700 mA Output Current per Channel
- Independent Over-Current Protection for Each Driver
- Thermal Protection for Device and Each Driver
- Low Output-Saturation Voltage
- Integral Output Flyback Diodes
- TTL and 5 V CMOS Compatible Inputs

2559 PROTECTED QUAD POWER DRIVER

Selection Guide

Part Number	Pb-free	Package	Ambient Temperature (°C)
UDN2559B	—	16-pin DIP, exposed tabs	–20 to 85
UDN2559B-T	Yes	16-pin DIP, exposed tabs	
UDN2559EB	—	28-lead PLCC	
UDN2559EB-T	Yes	16-pin DIP, exposed tabs	
UDN2559LB	Yes	16-lead SOIC	
UDN2559LB-T	Yes	16-lead SOIC	
UDQ2559B	—	16-pin DIP, exposed tabs	–40 to 85
UDQ2559B-T	Yes	16-pin DIP, exposed tabs	
UDQ2559LB	—	16-lead SOIC	
UDQ2559LB-T	Yes	16-lead SOIC	
UDK2559B	—	16-pin DIP, exposed tabs	–40 to 125
UDK2559B-T	Yes	16-pin DIP, exposed tabs	
UDK2559EB	—	28-lead PLCC	
UDK2559EB-T	Yes	28-lead PLCC	
UDK2559LB	—	16-lead SOIC	
UDK2559LB-T	Yes	16-pin DIP, exposed tabs	

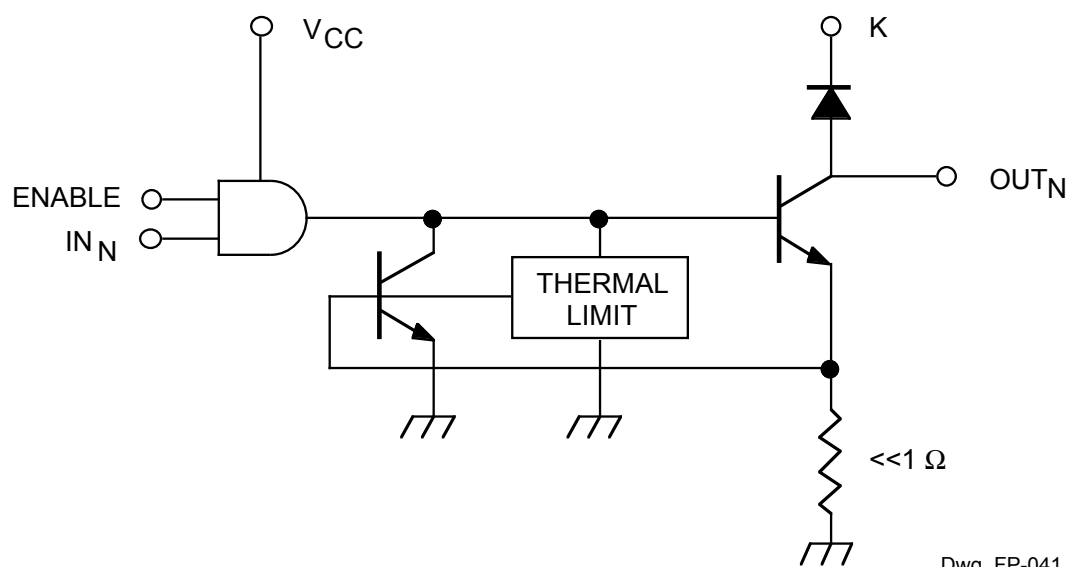
UDx2559LB



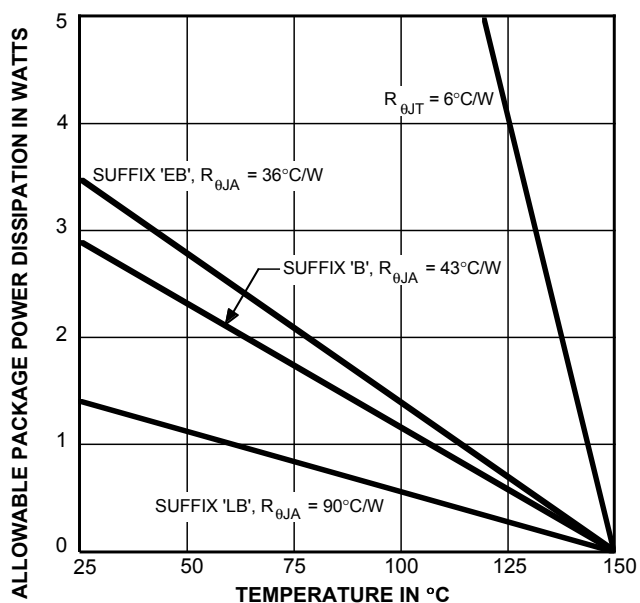
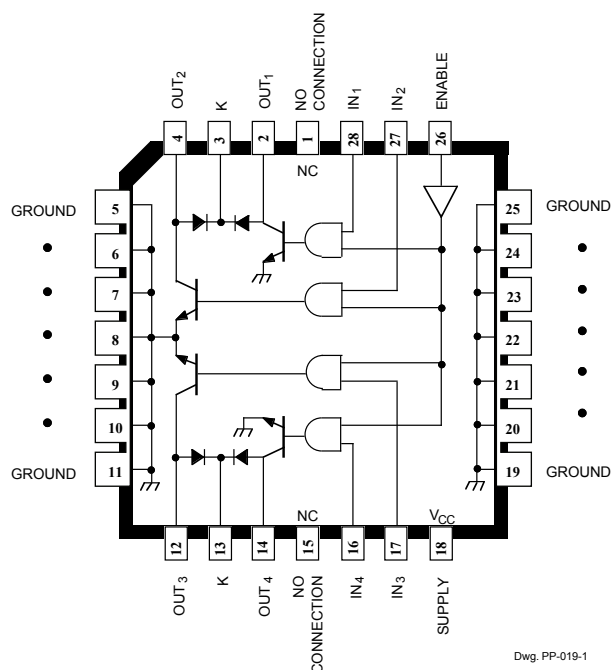
Dwg. PP-017-6

2559 PROTECTED QUAD POWER DRIVER

FUNCTIONAL BLOCK DIAGRAM (1 of 4 Channels)



UDx2559EB



$$P_D = (V_{OUT1} \times I_{OUT1} \times dc) + \dots + (V_{OUTn} \times I_{OUTn} \times dc) + (V_{CC} \times I_{CC}) = (T_J - T_A)/R_{\theta JA}$$

2559 PROTECTED QUAD POWER DRIVER

ELECTRICAL CHARACTERISTICS at $T_A = +25^\circ\text{C}$ (prefix 'UDN') or over operating temperature range (prefix 'UDK' or 'UDQ'), $V_{CC} = 4.75\text{ V}$ to 5.25 V

Characteristic	Symbol	Test Conditions	Limits			
			Min.	Typ.	Max.	Units
Output Leakage Current	I_{CEX}	$V_{OUT} = 50\text{ V}$, $V_{IN} = 0.8\text{ V}$, $V_{EN} = 2.0\text{ V}$	—	<1.0	100	μA
		$V_{OUT} = 50\text{ V}$, $V_{IN} = 2.0\text{ V}$, $V_{EN} = 0.8\text{ V}$	—	<1.0	100	μA
Output Sustaining Voltage	$V_{OUT(SUS)}$	$I_{OUT} = 100\text{ mA}$, $V_{IN} = V_{EN} = 0.8\text{ V}$	40	—	—	V
Output Saturation Voltage	$V_{OUT(SAT)}$	All Devices, $I_{OUT} = 100\text{ mA}$	—	—	300	mV
		All Devices, $I_{OUT} = 400\text{ mA}$	—	—	500	mV
		'B' & 'EB' Packages Only, $I_{OUT} = 600\text{ mA}$	—	—	700	mV
Over-Current Trip	I_{TRIP}		—	1.0	—	A
Input Voltage	Logic 1	$V_{IN(1)}$ or $V_{EN(1)}$	2.0	—	—	V
	Logic 0	$V_{IN(0)}$ or $V_{EN(0)}$	—	—	0.8	V
Input Current	Logic 1	$V_{IN(1)}$ or $V_{EN(1)} = 2.0\text{ V}$	—	—	40	μA
	Logic 0	$V_{IN(0)}$ or $V_{EN(0)} = 0.8\text{ V}$	—	—	-10	μA
Total Supply Current	I_{CC}	All Outputs ON, $V_{IN}^* = V_{EN} = 2.0\text{ V}$	—	—	80	mA
		All Outputs OFF	—	—	5.0	mA
Clamp Diode Forward Voltage	V_F	$I_F = 1.0\text{ A}$	—	—	1.7	V
		$I_F = 1.5\text{ A}$	—	—	2.1	V
Clamp Diode Leakage Current	I_R	$V_R = 50\text{ V}$, $D_1 + D_2$ or $D_3 + D_4$	—	—	50	μA
Turn-On Delay	t_{PHL}	$I_{OUT} = 500\text{ mA}$	—	—	20	μs
	t_{PLH}	$I_{OUT} = 500\text{ mA}$	—	—	20	μs
Thermal Limit	T_J		—	165	—	$^\circ\text{C}$

Typical Data is for design information only.

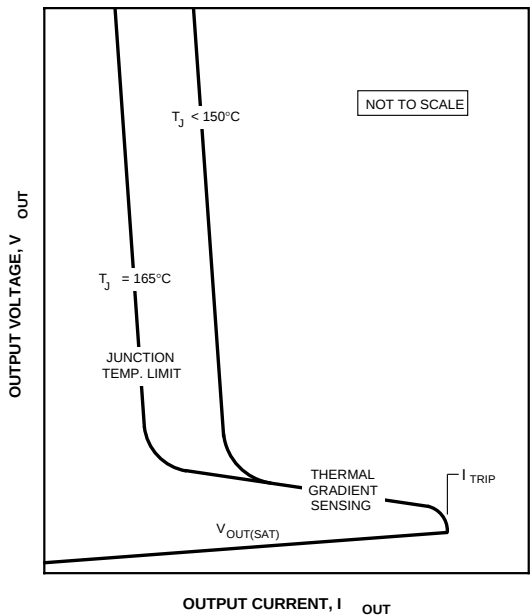
Negative current is defined as coming out of (sourcing) the specified terminal.

As used here, -100 is defined as greater than +10 (absolute magnitude convention) and the minimum is implicitly zero.

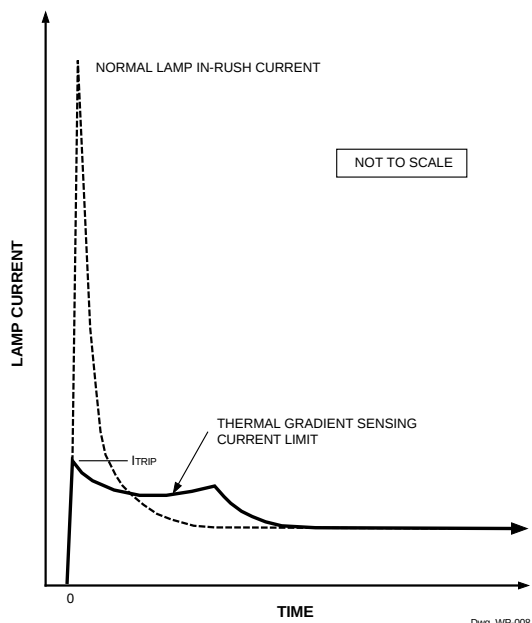
* All inputs simultaneously, all other tests are performed with each input tested separately.

2559 PROTECTED QUAD POWER DRIVER

TYPICAL OUTPUT CHARACTERISTIC



TYPICAL OUTPUT BEHAVIOR



CIRCUIT DESCRIPTION AND APPLICATION

INCANDESCENT LAMP DRIVER

High incandescent lamp turn-ON/in-rush currents can contribute to poor lamp reliability and destroy semiconductor lamp drivers. Warming or current-limiting resistors protect both driver and lamp but use significant power either when the lamp is OFF or when the lamp is ON, respectively. Lamps with steady-state current ratings up to 700 mA can be driven by these devices without the need for warming (parallel) or current-limiting (series) resistors.

When an incandescent lamp is initially turned ON, the cold filament is at minimum resistance and would normally allow a 10x to 12x in-rush current. With these drivers, during turn-ON, the high in-rush current is sensed by the internal low-value sense resistor. Drive current to the output stage is then diverted by the shunting transistor, and the load current is momentarily limited to approximately 1.0 A. During this short transition period, the output current is reduced to a value dependent on supply voltage and filament resistance. During lamp warmup, the filament resistance increases to its maximum value, the output stage goes into saturation and applies maximum rated voltage to the lamp.

INDUCTIVE LOAD DRIVER

Bifilar (unipolar) stepper motors, relays, or solenoids can be driven directly. The internal flyback diodes prevent damage to the output transistors by suppressing the high-voltage spikes that occur when turning OFF an inductive load.

For rapid current decay (fast turn-OFF speeds), the use of Zener diodes will raise the flyback voltage and improve performance. However, the peak voltage must not exceed the specified minimum sustaining voltage ($V_{SUPPLY} + V_Z + V_F \leq V_{OUT(SUS)}$).

FAULT CONDITIONS

In the event of a shorted load, the load current will attempt to increase. As described above, the drive current to the affected output stage is reduced, causing the output stage to go linear, limiting the peak output current to approximately 1 A. As the power dissipation of that output stage increases, a thermal gradient sensing circuit will become operational, further decreasing the drive current to the affected output stage and reducing the output current to a value dependent on supply voltage and load resistance.

Continuous or multiple overload conditions causing the chip temperature to reach approximately 165°C will result in an additional reduction in output current to maintain a safe level.

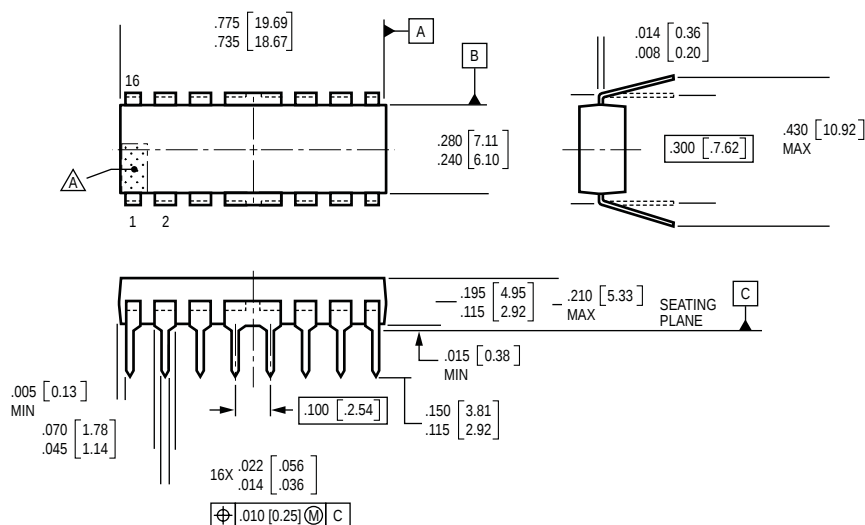
If the fault condition is corrected, the output stage will return to its normal saturated condition.

2559 PROTECTED QUAD POWER DRIVER

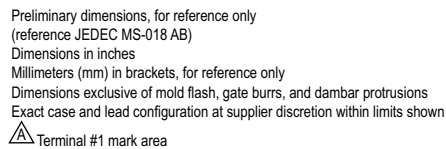
B Package, 16-pin DIP with internally fused pins 4, 5, 12, and 13 and external thermal tabs

Preliminary dimensions, for reference only
Dimensions in inches
Metric dimensions (mm) in brackets, for reference only
(reference JEDEC MS-001 BB)
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown

 Terminal #1 mark area

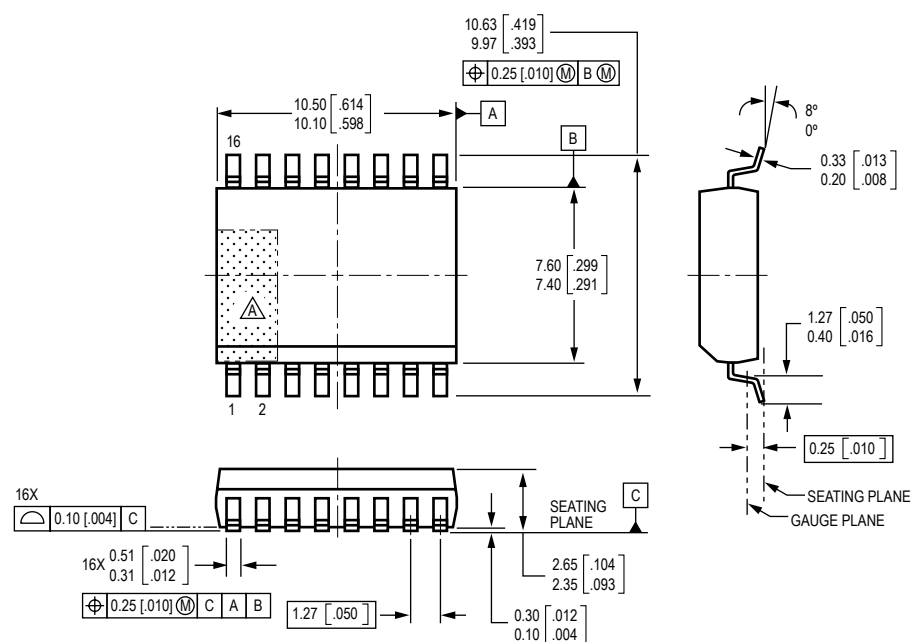


EB Package, 28-pin PLCC
with internally fused pins 5 through 11 and 19 through 25



2559 PROTECTED QUAD POWER DRIVER

LB Package, 16-pin SOIC with internally fused pins 4 and 5, and 12 and 13



Preliminary dimensions, for reference only
 Dimensions in millimeters
 U.S. Customary dimensions (in.) in brackets, for reference only
 (reference JEDEC MS-013 AA)
 Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
 Exact case and lead configuration at supplier discretion within limits shown

△ Terminal #1 mark area

2559
PROTECTED
QUAD POWER DRIVER

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